## **Supplementary Information for**

## Local Kondo-Scattering in 4*d*-electron RuO<sub>x</sub> Nanoclusters on Atomically-Resolved Ultrathin SrRuO<sub>3</sub> Films

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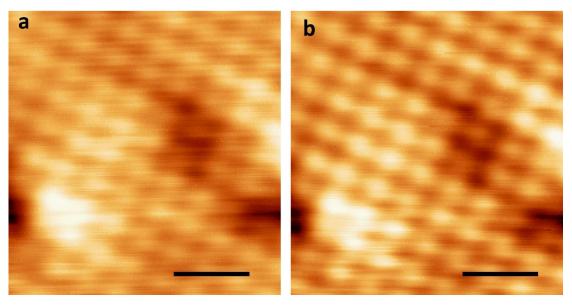
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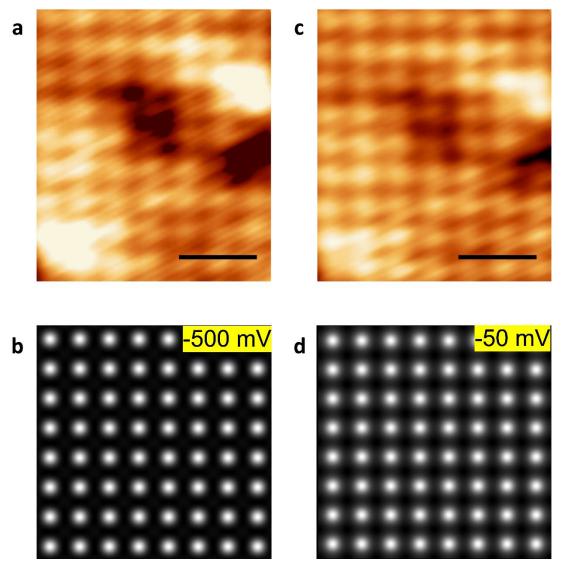
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**Figure S1. Sample-bias dependent STM images.** STM images measured at the same location with sample bias  $V_b$ = -500 mV (a) and  $V_b$ = -50 mV (b),  $I_t$  = 200 pA. Scale bar is 1 nm.



**Figure S2.** Experimental (a) and calculated (c) STM images with  $V_b$ =-500 mV. Experimental (b) and calculated (d) STM images with  $V_b$ =-50 mV. Scale bar is 1 nm.

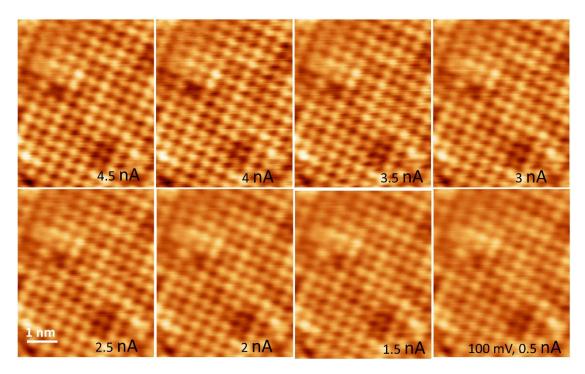
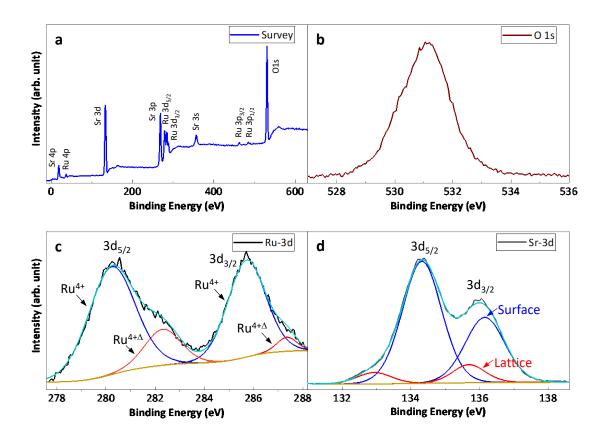
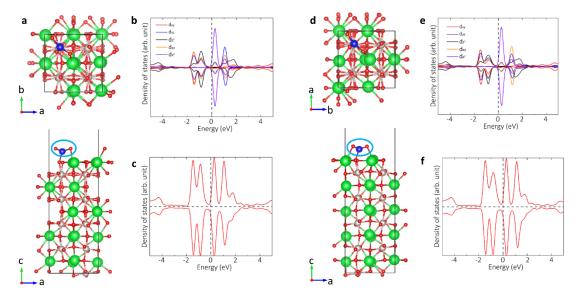


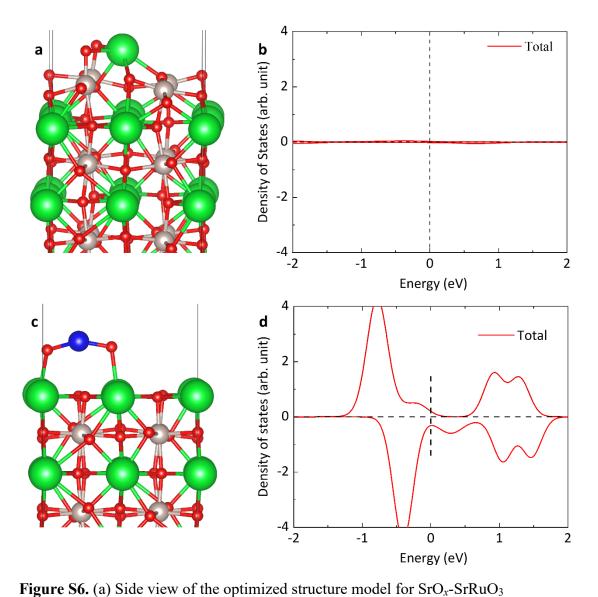
Figure S3. Tip-sample-distance dependent STM images. STM images measured at the same location with  $V_b$ = 100 mV fixed,  $I_t$  varies from 0.5 nA to 4.5 nA, no atomic arrangement change is observed.



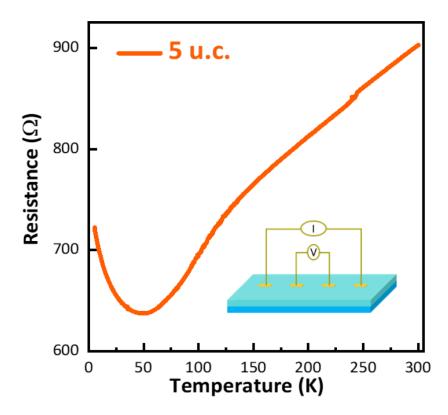
**Figure S4.** Surface composition analysis. (a) Grazing incidence X-ray photoelectron spectroscopy of the surface chemical composition of ultrathin SrRuO<sub>3</sub> thin film. (b) O 1s XPS spectrum. (c) Ru-3d XPS spectrum. (d) Sr-3d XPS spectrum.



**Figure S5. DFT calculations.** (a) Top and side views of the optimized structure model for RuO<sub>x</sub>-SRO adsorption system. Here we use blue atom to denote the adsorbed Ru (dashed circle). The PDOS (b) of the adsorbed Ru atom and the total DOS (c) of adsorbed Ru atom, with 4*d*-orbital-resolved  $e_g(d_{xy}, d_{yz}, d_{xz})$  and  $t_{2g}(d_{x^2}, d_{z^2})$  bands. (d) Top and side views of the optimized structure model for another RuO<sub>x</sub>-SRO adsorption system. The PDOS (e) of the adsorbed Ru atom and the total DOS (f) of adsorbed Ru atom, with 4*d*-orbital-resolved  $e_g(d_{xy}, d_{yz}, d_{xz})$  and  $t_{2g}(d_{x^2}, d_{z^2})$  bands. In both cases, spin-down states were filled more than the spin-up states near the  $E_F$ , and thus the net magnetization is produced. The Sr, Ru and O atoms in the bulk are denoted with green, grey and red spheres, respectively.



adsorption system. (b) The total PDOS of adsorbed Sr atom. (c) Side view of the optimized structure model for  $RuO_x$ -SrRuO<sub>3</sub> adsorption system. Here we use blue atom to denote the adsorbed Ru. (d) The total PDOS of adsorbed Ru atoms. The Sr, Ru and O atoms in the bulk are denoted with green, grey and red spheres, respectively.



**Figure S7.** Temperature-dependent resistance. The inset is the schematic of four-probe method.  $T_{\rm K} \sim 50~{\rm K}$  can be revealed.